Cyclotron Resonance of an Interacting Polaron G as in a Quantum Well. Magneto-Plasmon-Phonon Mixing

S.N.Klim in and J.T.Devreese

Theoretische Fysica van de Vaste Sto en, Universiteit Antwerpen (U.I.A.), B-2610 Antwerpen, Belgium (Dated: August 26, 2003)

A bstract

Cyclotron-resonance (CR) spectra of a gas of interacting polarons con ned in a GaAs/AlAs quantum well are theoretically investigated taking into account the magneto-plasm on-phonon mixing and band nonparabolicity. Contributions of dierent magneto-plasm on-phonon modes to the total magneto-polaron coupling strength are investigated as a function of the electron density. It is con rmed theoretically, that the resonant magneto-polaron coupling in a high-density GaAs/Alas quantum well occurs near the GaAsTO-phonon frequency rather than near the GaAsLO-phonon frequency. Calculated CR spectra are in agreement with recent experimental data.

I. INTRODUCTION

The electron-LO-phonon interaction plays an important role in the optical properties of polar sem iconductors and ionic crystals (see, for review, Refs. [1, 2, 3, 4, 5]). The application of an external magnetic eld adds new features to the optical absorption spectra of these materials. When the cyclotron frequency!_c is close to the LO-phonon frequency, resonant magneto-polaron coupling (i. e., anticrossing of zero-phonon and, e. g., one-phonon states of the polaron system) occurs [6]. Experiments on the cyclotron resonance (CR) in bulk [7] and quasi-2D [8, 9, 10] systems give clear evidence of this resonant magneto-polaron coupling. However, CR measurements on semiconductor quantum wells with high electron density [11, 12] reveal that the anticrossing occurs near the TO-phonon frequency rather than near the LO-phonon frequency. In Ref. [12], on the basis of a model dielectric function for a 3D medium, it was suggested that in a GaAs/Alas quantum well with high electron density, there may exist longitudinal modes, with energies close to the TO-phonon frequency, which are active in CR.

Another consequence of high electron densities combined with the nonparabolicity of the conduction band is a splitting of the CR lines [13, 14, 15, 16, 17]. It was shown in Ref. [16], that the one-particle approximation fails to interpret the oscillator strengths of the split CR lines.

Many-polaron CR in a 2D polaron gas was investigated theoretically in Ref. [18] using the memory-function technique [19]. In Ref. [10], this technique was applied to a polaron gas in a quantum well. The CR spectra of polarons in a quantum well were calculated in Ref. [20] and applied in Refs. [21, 22] taking into account the electron-phonon interaction for both bulk-like and interface phonon modes. To quantitatively explain the CR data for a high-density polaron gas, as observed in Ref. [12], it is necessary to take into account many-body e ects.

In the present paper, the CR spectra of an arbitrary-density polaron gas in a quantum well are calculated using the many-body memory-function technique [19]. The approach developed in Refs. [18, 20] is extended here to a system of electrons conned in a quantum well and interacting with magneto-plasmon-phonon modes. Within this method, we take into account the electron-electron interaction, the static and dynamic screening of the electron-phonon interaction [18], the magneto-plasmon-phonon mixing [23], the band nonparabolicity and the phonon spectra specic for a quantum well.

The paper is organized as follows. In Sec. II, the optical conductivity for a polaron gas in a quantum well is derived. In Sec. III, we discuss the calculated CR spectra and compare them with experimental data for a GaAs/AlAs quantum well. Sec. IV contains the conclusions.

II. THEORETICAL APPROACH

A. Ham iltonian

We consider a nite-barrier quantum well of width d: The quantum well (medium 1) with high-frequency dielectric constant \mathbf{I}_1 is placed into a matrix (medium 2) with high-frequency dielectric constant \mathbf{I}_2 : B oth these media are supposed to be polar. An external magnetic eld B is applied parallel to the z-axis. The symmetric gauge is chosen for the vector potential

of the magnetic eld,

A
$$(r) = \frac{1}{2} [r \ B]$$
: (1)

The Ham iltonian describing the system, which consists of electrons interacting with α

$$H = \sum_{\substack{n \text{ lm} \\ n \text{ lm}}} E_{n1} a_{n \text{ lm}}^{+} a_{n \text{ lm}} + \sum_{\substack{n \text{ lm} \\ n \text{ lm}}} v_{n \text{ lm}} a_{n \text{ lm}} + \sum_{\substack{n \text{ lm} \\ n \text{ lm}}} v_{n \text{ lm}} a_{n \text{ lm}} a_{n \text{ lm}} + \sum_{\substack{n \text{ lm} \\ n \text{ lm}}} v_{n \text{ lm}} a_{n \text{ lm}} a_{n$$

where $a_{n\,lm}^+$ ($a_{n\,lm}$) is a creation (annihilation) operator for an electron in the one-particle state with energy E $_{n\,l}$ and with the wave function

$$\lim_{n \to \infty} (;';z) = _{n}(z) _{lm}(;');$$

$$\lim_{m \to \infty} (;') = \frac{1}{2} e^{im'} _{lm}();$$
(3)

Here, the function $_n$ (z) corresponds to the n-th size-quantized subband for motion along the z-axis, while $_{lm}$ (;') characterizes the \in-plane" motion of an electron with a de nite z-projection m of its angular momentum, l is the Landau level quantum number.

The phonon frequencies! $_{\rm q}$ and the amplitudes of the electron-phonon interaction $_{\rm q}$ are explicitly derived in Refs. [20, 30]. The index refers to the phonon branches, q is the phonon two-dimensional wave vector, $b_{\rm q}^{\dagger}$ (b $_{\rm q}$) is a phonon creation (annihilation) operator. $_{\rm nk}$ (q) is the electron density operator

with the matrix element

$$e^{iq} = \lim_{m \to 1^{n_m}} e^{iq} = \int_{0}^{x} d d e^{iq} = \lim_{m \to \infty} (;') e^{iq} = \lim_{m \to \infty} (;') e^{iq} = (ig) = (i$$

In the Ham iltonian (2), V_C (k_1 ; n_1 ; n_2 ; k_2 jq) is the matrix element of the electron-electron interaction potential

$$V_{C} (k_{1}; n_{1}; n_{2}; k_{2}; q) = \begin{cases} Z_{1} & Z_{1} \\ dz & dz^{0} V_{C} (q; z; z^{0}) \\ & & \\ &$$

S is the area of the quantum well in the xy-plane, N [:::] is a normal product of operators. The two-dimensional Fourier amplitude V_C (q;z;z⁰) of the electron-electron interaction potential, special for the quantum well, diers from the corresponding expression for the Coulomb potential in bulk owing to the presence of the electrostatic image forces, which appear as long as " $_1 \in$ " $_2$ (see, e.g., Refs. [27, 28, 29]).

W ithin the local parabolic band approximation [24, 25], nonparabolicity is considered as a small perturbation. Consequently, the wave function $_{lm}$ () (3) for an electron in a magnetic eld takes the form

$$\frac{S}{2K!} = \frac{m_{b}!_{c}}{(jm j + K)!} = \frac{m_{b}!_{c}}{2^{c}} = \frac{jm j + 1}{2} = \frac{m_{b}!_{c}}{4^{c}} = \frac{m_{b}!_{c}}{4^{c}} = \frac{m_{b}!_{c}}{2^{c}} = \frac{m_{b}$$

with the Laguerre polynom ial $L_K^{(a)}$ (z). Here, the cyclotron frequency ! $_{\text{c}}$ = eB = (m $_{\text{b}}$ c) corresponds to the mass m $_{\text{b}}$ given by [20]

$$m_b = \frac{m_{b1}m_{b2}}{P_w m_{b2} + P_b m_{b1}};$$
(8)

where P_w (P_b) is the probability to nd the electron inside (outside) the quantum well, and m $_{\rm bi}$ (i = 1;2) is the electron band m ass at the bottom of the conduction band in the i-th m edium . The energies of the spin-dependent electron states are

$$E_{n1} = E_{n1} + g_B B ; \qquad (9)$$

where g is the Lande factor, $_{\rm B}$ is the Bohr magneton, = 1=2 is the spin projection. The energy levels ${\rm E}_{\rm nl}$ corresponding to the wave functions $_{\rm nlm}$ (;';z) in (3) are calculated using the ve-band k p model [6].

B. Optical conductivity

W ithin the mem ory-function form alism, the real part of the frequency-dependent conductivity (in the Faraday con guration) in the local parabolic band approximation, can be written as [18, 25]

Re
$$(!) = \frac{n_S e^2}{m_B} \text{Im} \frac{1}{! !_C} \frac{1}{(!;!_C) = ! + i}$$
 (! +0);

where $n_{\rm S}$ is the 2D electron density, and (!) is the memory function [18]. To take into account the splitting of the CR peaks due to the nonparabolicity of the conduction band, Eq. (10) is generalized as follows:

Re
$$(!) = X_{n_1} Re_{n_1} (!);$$
 (11)

where each contribution Re $_{n1}$ (!), corresponding to the transitions (1! 1+ 1),

is calculated with the local parabolic band approximation. The transition frequency

$$!_{c}^{(nl)} = \frac{E_{n;l+1;} E_{nl}}{\sim}$$
 (13)

is used in Eq. (12) as distinct from the cyclotron frequency $!_{\rm c}$ in Eq. (10). The weight $\{_{\rm nl}$ is proportional to the number of open channels for the transitions (1! l+ 1). The normalized weights $\{_{\rm nl}$ are

$$\{_{n1} = \frac{f_{n1} (1 f_{n;l+1;})}{\int_{n^{0;l^{0}; 0}} f_{n^{0}l^{0}} (1 f_{n;l+1; 0})};$$
(14)

where f_{n1} is the Ferm i occupation number. The memory function (!;!c) takes the form (cf. Refs. [18, 20])

$$(!;!_{c}) = \begin{cases} X & X & Z \\ \frac{d^{2}q}{(2)^{2}} \frac{(_{q})_{nk}^{2} q^{2}}{n_{S} \sim m_{b}^{2} (q)} \\ \frac{Z^{I}}{dte^{-t} e^{i!t}} & 1 \text{ Im } [D (q;t) G_{nk} (q;t)] \quad (! + 0); \end{cases}$$
(15)

where (q) is the static screening factor [8]. D (qt) is the phonon G reen's function

D
$$(q;t)$$
 i (t) $b_{,q}(t)$ $b_{,q}^{\dagger}(0)$ + $b_{,q}^{\dagger}(t)$ $b_{,q}(0)$ (16)

and G_{nk} (q;t) is the electron density-density G reen's function

$$G_{nk}(q;t) = i(t) \frac{1}{S}_{nk}(q;t)_{nk}^{+}(q;0)$$
 (17)

with the Heaviside step function (t). The averaging in Eqs. (16) and (17) is performed on the equilibrium statistical operator of the electron-phonon system.

In the present paper, we apply the method presented above to the case of a G aA s/A lA s quantum well, where the weak-coupling regime is realized. To obtain (!;!c) to second order in perturbation theory, the electron density-density G reen's function G_{nk} (q;t) can be calculated neglecting the electron-phonon interaction. The electron-electron interaction is taken into account in the random-phase approximation (RPA) following Ref. [31], where plasm on modes are derived for electrons in a layer. As a result, we arrive at the following set of equations in the Fourier representation

$$[_{nn_{1} kk_{1}} \quad P_{nk} (q;!) V_{C} (k;n;k_{1};n_{1};q)] G_{n_{1}k_{1};n_{K}}^{R} (q;!) = _{nn_{k}} \sim P_{nk} (q;!) :$$
 (18)

Here, the auxiliary retarded G reen's function $G_{nk,nR}^{R}$ (q;!) is determined as

$$G_{nk;nk}^{R} (q;!) = \frac{i}{S} \sum_{n=1}^{Z} Dh \qquad iE \\ n_{k} (q;t); + (q;0) e^{i!t} dt \quad (! + 0): \qquad (19)$$

The RPA structure factor P_{nk} (q;!) is proportional to the retarded density-density G reen's function of non-interacting electrons in the quantum well in the presence of a magnetic eld. It is calculated explicitly, using the second-quantization representation of the density operators (4), and takes the form

where $!_{kn}$ is the transition frequency between the k-th and the n-th size-quantized subbands. The set of equations (18) is valid for arbitrary electron density. The G reen's function

The set of equations (18) is valid for arbitrary electron density. The G reen's function G_{nk} (q;!) is obtained from G_{nk}^R (q;!) using the K ram ers-K ronig dispersion relations and the relation, which follows from the analytical properties of G reen's functions,

$$\operatorname{Im} G_{nk}^{R}(q;!) = 1 \quad e^{!} \operatorname{Im} G_{nk}(q;!);$$
 (21)

where $1=(k_BT)$. Further on, we consider the case of a su ciently narrow quantum well, when only the lowest size-quantization subband (n=1) is led, and the transition frequency $!_{21}$ $!_{Li}$; where $!_{Li}$ is the LO-phonon frequency in the i-th medium (i=1;2). Under these conditions, transitions of an electron to other subbands can be neglected. This results in the explicit solution

$$G_{11}^{R}(q;!) = \frac{\sim P_{11}(q;!)}{1 \quad \forall_{c}(q) P_{11}(q;!)}$$
(22)

with V_c (q) V_c (1;1;1;1jq):

The phonon retarded G reen's function is calculated within the random -phase approximation taking into account the magneto-plasmon-phonon mixing (cf. Ref. [23]). In the present case of a narrow quantum well, we take into account the mixing of phonons with intrasubband magneto-plasmons only. In this approximation, disentangling a set of coupled D yson equations leads to:

$$D^{R} (q;!) = \frac{2 !_{R} + \frac{j(_{R})_{11} j^{2}}{2} G_{11}^{R} (q;!)}{(! + i)^{2} !_{R}^{2} 2!_{R} \frac{j(_{R})_{11} j^{2}}{2} G_{11}^{R} (q;!)} \qquad (! + 0):$$
 (23)

The poles of this G reen's function are the roots of the equation

$$!^{2} \quad !^{2}_{,q} \quad 2!_{,q} \frac{(_{,q})_{11}^{2}}{^{2}_{,q}} ReG_{11}^{R} (q;!) = 0$$
 (24)

and they determ ine the spectrum of mixed magneto-plasmon-phonon excitations in the quantum well. Let $_{;j}$ (q) denote the positive roots of Eq. (24). Using G_{11}^{R} (q;!) given by Eq. (22), with the structure factor (20), we note that the retarded G reen's function (23) can be expanded as a series

$$D^{R}(q;!) = \sum_{j=1}^{X} A_{jj}(q) \frac{1}{! + j(q) + i} \frac{1}{! + j(q) + i} ; ! + 0; (25)$$

where A $_{;j}$ (q) is the residue of D R (q;!) at ! = $_{;j}$ (q): The G reen's function D (q;!) is obtained from D R (q;!) using relations between Im D R (q;!) and Im D (q;!) similar to Eq. (21), and the K ram ers-K ronig dispersion relations. As a result, the G reen's function D (q;!) can be written down explicitly,

$$D (q;!) = \frac{X}{1 + 0} \frac{A_{ij}(q)}{1 + e_{ij}(q)} \frac{1}{!} + \frac{e_{ij}(q)}{! + i} + \frac{e_{ij}(q)}{! + i} ; + 0: (26)$$

It is seen from Eqs. (15) and (26), that the parameter

$$W_{ij}(q) = (g_{ij})_{11}^{2} A_{ij}(q)$$
 (27)

determ ines the strength of the coupling between an electron and the (; j)-th magnetoplasm on-phonon mode characterized by the wave vector q.

III. RESULTS AND DISCUSSION

U sing the method developed in the previous section, the magneto-plasmon-phonon frequencies and the magneto-absorption spectra of a G aA s/A IA s quantum well are now calculated numerically. Within this approach, the CR peaks are proportional to delta-functions because of the discrete energy spectrum of an electron in a quantum well in the presence of a magnetic eld (see, e.g., Ref. [20]). In what follows, we introduce in Eq. (15) a nite broadening of the Landau levels instead of the in nitesimal parameter !+0. Here, we choose the value $=0.01!_{\rm L1}$, which corresponds to the linewidth of the CR peaks in the experiment of Ref. [12]. The material parameters used for the present calculation are listed in Table 1.

Table 1. M aterial pa	ram eters	used	for the	calculation	of the
m agneto-absorption	spectra	ofa G	aA s/A]	A s quantum	well

Param eter	GaAs	AlAs	
LO-phonon energy, m eV	36.3 [12]	50.09 [32]	
TO-phonon energy, m eV	33.6 [12]	44.88 [32]	
Electron band mass, in units	0.0653 [26]	0 15 B21	
of the electron m ass in the vacuum	0.0003 [20]	0.13 [22]	
High-frequency dielectric constant	10.89 [32]	8.16 [32]	
Electron-phonon coupling constant	0.068 [3]	0.148 [32]	

The value 0.915 eV [20] is used for the A A s/G aAs potential barrier. In the numerical calculation, we use a form ula for the energy levels in a non-parabolic conduction band taken from Refs. [25, 26]

$$E_{n1} = \frac{E_0}{2} \qquad 1 + 4 \frac{E_{n1}^0}{E_0} \qquad 1$$
 (28)

with the e ective energy gap E $_0$ = 0:98 eV [26] and with E $_{\rm n1}^0$ = $\sim !_{\rm c}$ 1+ $\frac{1}{2}$ + $_{\rm n}$, where $_{\rm n}$ is a size-quantized energy level characterizing the motion along the z-axis.

A coording to Ref. [20], the following phonon branches give contributions to the CR spectra in a quantum well: (i) bulk-like phonons with frequency $!_{1,1}$, (ii) sym metric interface phonons with frequencies !s; (q) given by Eq. (7) of Ref. [20]. In a similar way, the magnetoplasm on-phonon modes in a quantum well can be classied into bulk-like and interface m odes. The frequencies of these m odes depend on the electron density and on the m odulus q of the 2D wave vector q. As follows from our calculations, the modes, whose wave vectors lie $(m_b!_{L1}=\sim)^{1=2}$; give the dom inant contribution to the 2q; where q in the region with q m agneto-optical absorption. In Fig. 1, frequencies of six m ixed m agneto-plasm on-phonon m odes, which contribute signi cantly to the cyclotron-resonance spectrum, are plotted as a function of the electron density for $!_c = 0.8!_{L1}$ and for q = 2q. In the low-density \lim it, as seen from Fig. 1, the phonon modes do not m ix with the magneto-plasmons. At n_s ! 0; the frequencies of the bulk-like and of two symmetric interface magneto-plasmon-phonon m odes tend to $!_{L1}$ and $!_{S}$; (q), respectively (cf. Ref. [20]). W ith increasing density n_{S} ; the m agneto-plasm on branch splits into three m odes (shown by black curves). When the density

rises further, anticrossing of phonon and magneto-plasm on frequencies is to be expected between 10^{11} cm 2 . $n_{\rm S}$. 10^{12} cm 2 . This anticrossing allows us to distinguish between the lower-frequency modes (black curves) and the higher-frequency modes (red curves). Finally, for $n_{\rm S}$ & 10^{12} cm 2 , the three higher frequencies tend to the magneto-plasm on frequency, which behaves as $n_{\rm S}^{1=2}$; and the three lower frequencies are close to $!_{\rm T1}$ and to $!_{\rm S}$; (q), respectively. The latter two magneto-plasm on-phonon frequencies are actually slightly reduced with respect to $!_{\rm S}$; (q). The appearance of the branch with frequency close to $!_{\rm T1}$ instead of $!_{\rm L1}$ is due to the screening of the electron-phonon interaction by the plasm a vibrations.

In Fig. 2, the relative contributions of dierent magneto-plasmon-phonon modes to the total magneto-polaron coupling strength

$$w_{ij}(q) = \frac{w_{ij}(q)}{v_{ij}(q)}$$
 (29)

are plotted as a function of n_s for $q=2q_p$: In the low-density lim it, the plasm a vibrations give a vanishing contribution to w_{ij} (q). In this case, the electrons interact only with phonons. For increasing electron density, the strength of the interaction of an electron with the lower-frequency magneto-plasmon-phonon modes rises, while that for the higher-frequency modes decreases. For a 10-nm GaAs/Alas quantum well, the contribution of the interface magneto-plasmon-phonon modes into the CR spectra is smaller than that of the bulk-like modes. Nevertheless, the interaction of an electron with the interface modes is not negligible.

In Ref. [12], CR spectra are measured for the absolute transmission T (!); which is related to the optical absorption coe cient by

The optical absorption coe cient is proportional to Re (!),

$$(!) = \frac{4}{cn(!)} Re(!);$$
 (31)

where n (!) is the refractive index. In Fig. 3, we compare the experimental [12] transm ission spectra with the transm ission spectra calculated in the present work for a polaron gas with electron density $n_{\rm S}=128-10^{12}$ cm 2 in a 10-nm G aA s/A IA s quantum well. Reliable comparison of our theoretical results with the experimental data of Ref. [12] can be performed only outside a frequency band near $!_{\rm T1}$ (shown in Fig. 3 by the cross-hatched

area), because the experim ental spectra in this frequency region are obtained after the elimination of a strong absorption peak due to direct TO-phonon absorption in the substrate. It is not straightforward to extract information on the CR spectra in this frequency region. It is seen from Fig. 3, that outside the cross-hatched area the theoretical peak positions of the magneto-transmission spectra calculated in the present work reasonably compare with the experimental data of Ref. [12]. If one tunes the magnetic eld within the error bar, the agreement between theory and experiment can be improved. The remaining difference between theoretical and experimental peak positions can be explained by possible deviation of the values of the band parameters (the electron band mass and the electron energy gap) in a GaAs/AlAs quantum well from those in bulk.

Thee ect of them agneto-plasm on-phonon m ixing is clearly manifested in the CR spectra, as seen, e. g., from the plot corresponding to a magnetic eld B = 22.25 T, for which $!_{\text{C}} \quad !_{\text{T}1} \quad 33.6$ m eV . For this value of B, the intensities of the peaks below $!_{\text{T}1}$ and above $!_{\text{T}1}$ are comparable both in the experiment [12] and in the present theory. Such a behavior is typical for resonant magneto-polaron coupling near $!_{\text{T}1}$ rather than near $!_{\text{L}1}$.

The splitting of the CR peaks manifested in Fig. 3 re ects the nonparabolicity of the conduction band. In the experimental CR spectra [12], the higher-frequency and lowerfrequency components of the split peaks are denoted as A-resp. B-components. The higherfrequency component of each split peak corresponds to the transitions between the Landau levels (0! 1), while the lower-frequency component corresponds to the transitions (1! 2). With increasing magnetic eld strength, the distance between Landau levels rises, so that the upper led level (l = 1) becomes less populated. As a result, the relative intensity of the lower-frequency peak diminishes. It is shown in Ref. [16], that the observed relative oscillator strengths of the split CR peaks are not consistent with the one-particle theoretical picture. The one-particle theories (e. g., Refs. [36, 37]) overestim ate the lower-frequency peak intensity as compared to experiment. In particular, for a lling factor one-particle approximation predicts $I_{(1; 2)}=I_{(0; 1)}$ 2, which contradicts the experimental CR data for high electron densities [16], where this ratio is close to 1. It is noteworthy, that for = 3; the coe cients { $_{nl}$ given by (14) for l=0 and for l=1 are equal to each other, while the contributions Re_{nl} (!) only slightly depend on the Landau level quantum number. Therefore, for = 3; our theory gives $I_{(1!\ 2)}=I_{(0!\ 1)}$ 1, in agreem ent with Ref. [16].

In Fig. 4, we plot a set of our theoretical magneto-absorption spectra for a GaAs/Alas quantum well as a colorm ap. This map shows the magneto-absorption intensity as a function of both the magnetic eld and the frequency. For comparison, the experimental peak position taken from Fig. 3 of Ref. [12] are shown in the same graph. For the peaks with B/172 T (indicated by crosses) the splitting due to the band nonparabolicity is not resolved experimentally. It is seen from Fig. 4 that, for the high-density electron gas, anticrossing of the CR spectra occurs near $!_{T1}$ both for the experimental and for the calculated CR spectra. Starting from large B; a set of peaks with $! > !_{T1}$ are pinned towards $!_{T1}$ from above, while starting from B 0; another set of peaks are pinned from below to a frequency slightly larger than $!_{T1}$:

For a low-density polaron gas in a G aA s/A IA s quantum well, it was found [20], that the resonance frequencies, calculated taking into account the interaction of electrons with both bulk-like and interface phonons, appreciably deviate from those found for the interaction with bulk LO phonons only. In particular, due to interface phonons, a resonance frequency appears between $!_{L1}$ and $!_{T1}$ (see Fig. 7 of Ref. [20]). In the present work, we take into

account, in addition to the e ects due to the interaction of electrons with bulk-like and interface phonons, the many-body e ects, which ensure the shift of the resonance frequency towards $!_{\text{T1}}$; when the electron density is high enough.

The splitting of the magneto-absorption peaks due to the band nonparabolicity, observed in the experiment for ! < ! $_{T1}$; continues in the theoretically calculated spectra also in the region ! > ! $_{T1}$. However, the intensity of the B-component for ! > ! $_{T1}$ is quite small.

IV. CONCLUSIONS

We have theoretically investigated cyclotron-resonance spectra for a polaron gas in a G aA s/A IA s quantum well with high electron density, taking into account (i) the electron-electron interaction and as a consequence the screening of the electron-phonon interaction, (ii) the magneto-plasm on-phonon mixing, (iii) the electron-phonon interaction with relevant phonon modes specific for the quantum well under consideration. As a result of the mixing, different magneto-plasm on-phonon modes appear in the quantum well and contribute to the CR spectra. In the 10-nm G aA s/A IA s quantum well (investigated experimentally in Ref. [12]), the interaction of an electron with the bulk-like modes is dominant. It is shown in the present work that, in the high-density polaron gas, the resonant magneto-polaron coupling, manifested in the CR spectra, takes place at a frequency close to the TO-phonon frequency in G aA s. This elect is in contrast with the cyclotron resonance of a low-density polaron gas in a quantum well, where anticrossing occurs near the LO-phonon frequency. Due to the band nonparabolicity, the CR spectrum of a high-density polaron gas in a quantum well is split into two components. The calculated CR-spectra are in agreement with experiment, in particular, with the results of Ref. [12].

A cknow ledgm ents

D iscussions with V.M. Fom in, G.M artinez and V.N.G ladilin are gratefully acknowledged. This work has been supported by the GOA BOF UA 2000, IUAP., FW O.V. projects G.0274.01N, G.0435.03, the W O.G.WO.025.99 (Belgium) and the European Commission GROW TH Programme, NANOMAT project, contract No. G5RD-CT-2001-00545.

^[*] Perm anent address: Department of Theoretical Physics, State University of Moldova, str. A. Mateevici 60, MD-2009 Kishinev, Republic of Moldova.

^[**] A lso at: Universiteit Antwerpen (RUCA), Groenenborgerlaan 171, B-2020 Antwerpen, Belgium and Technische Universiteit Eindhoven, P.B. 513, 5600 MB Eindhoven, The Netherlands.

^[1] Polarons and Excitons, edited by C.G.Kuper and G.D.W hit eld (O liver and Boyd, Edinburgh, 1963)

^[2] J.Appel, in: Solid State Physics, edited by F. Seitz, D. Tumbull, and H. Ehrenreich, Vol. 21, pp. 193–391 (1968).

^[3] Polarons in Ionic Crystals and Polar Semiconductors, edited by J. T. Devreese (North-Holland, Amsterdam, 1972).

^[4] J.T.Devreese, in: Encyclopedia of Applied Physics (VCH, Weihheim, 1996), Vol. 14, p. 383.

- [5] P. Calvani, Optical Properties of Polarons (Editrice Compositori, Bologna, 2001).
- [6] D. Larsen, Phys. Rev. 135, A 419 (1964); in Ref. [3], p. 237.
- [7] B.D.McCombe and R.Kaplan, Phys. Rev. Lett. 21, 756 (1968).
- [8] Y.H.Chang, B.D.McCombe, J.-M.Mercy, A.A.Reeder, J.Ralston and G.A.Wicks, Phys. Rev. Lett. 61, 1408 (1988).
- [9] J.P.Cheng, B.D.McCombe, and G.Brozak, Phys. Rev. B 43, 9324 (1991).
- [10] F.M. Peeters, X.Wu, J.T. Devreese, C.J.G.M. Langerak, J. Singleton, D.J. Barnes, and R.J. Nicholas, Phys. Rev. B 45, 4296 (1992).
- [11] M. Ziesmann, D. Heitmann, and L. L. Chang, Phys. Rev. B 35, 4541 (1987).
- [12] A.J.L.Poulter, J.Zeman, D.K.Maude, M.Potemski, G.Martinez, A.Riedel, R.Hey, and K.J.Friedland, Phys.Rev.Lett. 86, 336 (2001).
- [13] A.H.MacDonald and C.Kallin, Phys. Rev. B 40, 5795 (1989).
- [14] C.M. Hu, E. Batke, K. Kohler, and P. Ganser, Phys. Rev. Letters 75, 918 (1995).
- [15] C.M. Hu, T. Friedrich, E. Batke, K. Kohler, and P. Ganser, Phys. Rev. B 52, 12090 (1995).
- [16] M.Manger, E.Batke, R.Hey, K.J. Friedland, K.Kohler, and P.Ganser, Phys. Rev. B 63, 121203 (2001).
- [17] Yu.A.Bychkov and G.Martinez, Phys. Rev. B 66, 193312 (2002).
- [18] Wu Xiaoguang, F.M. Peeters, and J.T. Devreese, Phys. Rev. B 36, 9760 (1987).
- [19] H.Mori, Progr. Theor. Phys. 33, 423 (1965); 34, 399 (1965).
- [20] G.Q.Hai, F.M. Peeters, and J.T.Devreese, Phys.Rev.B 47, 10358 (1993).
- [21] Y.J.Wang, H.A.Nickel, B.D.McCombe, F.M.Peeters, J.M.Shi, G.Q.Hai, X.-G.Wu, T.J.Eustis, and W.Scha, Phys.Rev.Lett.79, 3226 (1997).
- [22] J.T.Devreese and F.M.Peeters, in \High Magnetic Fields in Semiconductor Physics II", ed. by G.Landwehr, Springer Series in Solid-State Sciences Vol. 87 (Springer Verlag, Heidelberg, 1989).
- [23] L.W endler and R.Pechstedt, J.Phys.: Condens.M atter 2, 8881 (1990).
- [24] D. Larsen, Phys. Rev. B 35, 9301 (1987).
- [25] X.Wu, F.M. Peeters, and J.T. Devreese, Phys. Rev. B 40, 4090 (1989).
- [26] P.P fe er and W. Zawadzki, Phys. Rev. B 53, 12813 (1996).
- [27] E.P. Pokatilov, S.I. Beril, and V.M. Fom in, Phys. Stat. Sol. (b) 147, 163 (1988).
- [28] E P Pokatilov, S.I.Beril, V M Fom in, V V K alinovskii, Phys. Stat. Sol. (b) 161, 603 (1990).
- [29] E.P.Pokatilov, V.M. Fom in, and S.I.Beril, Vibrational excitations, polarons and excitons in multilayer structures (Stiinta, Chisinau, 1990).
- [30] G.Q.Hai, F.M. Peeters, and J.T. Devreese, Phys. Rev. B 42, 11063 (1990).
- [31] W.H.Backes, F.M.Peeters, F.Brosens, and J.T.Devreese, Phys.Rev.B 45, 8437 (1992).
- [32] S.Adachi, J.Appl. Phys. 58, R1 (1985).
- [33] C.Kallin and B.I.Halperin, Phys. Rev. B 31, 3635 (1985).
- [34] B. Zhang, M. F. M. anger, and E. Batke, Phys. Rev. Letters 89, 039703 (2002).
- [35] V.V.A fonin, V.L.Gurevich, and R.Laiho, Phys. Rev. B 62, 15913 (2000).
- [36] K.L.Kobayashi and E.Otsuka, J.Phys.Chem.Solids 35, 839 (1974).
- [37] T. Ando, J. Phys. Soc. Japan 38, 989 (1975).

Figure captions

- Fig. 1 (color). Frequencies of magneto-plasmon-phonon modes in a 10-nm GaAs/Alas quantum well as a function of the electron density. The value $!_{\rm c} = 0.8!_{\rm L1}$ is taken for the cyclotron frequency. Solid, dashed and dash-dotted curves correspond to bulk-like, interface (GaAs) and interface (Alas) modes, respectively.
- Fig. 2 (color). Relative contributions of six magneto-plasm on-phonon modes to the total magneto-polaron coupling strength w (q) $_{,j}$ w $_{,j}$ (q) in a 10-nm G aAs/A IAs quantum well as a function of the electron density. The other modes are neglected, because their relative contribution is only about 10 4 of w (q): The notations are the same as those of Fig. 1.
- Fig. 3 (color). Experim ental and theoretical transm ission spectra, at di erent magnetic elds, for a 10-nm GaAs/AlAs quantum well with electron density $n_{\rm S}=1.28-10^2$ cm 2 . The black solid curves represent the experimental data of Ref. [12]. The red dashed curves correspond to the present theory.
- Fig. 4 (color). Color map of the cyclotron resonance spectra for a 10-nm GaAs/Alas quantum well. Symbols indicate the peak positions of the experimental spectra (which are taken from Fig. 3 of Ref. [12]). The dashed lines show LO-and TO-phonon frequencies in GaAs.

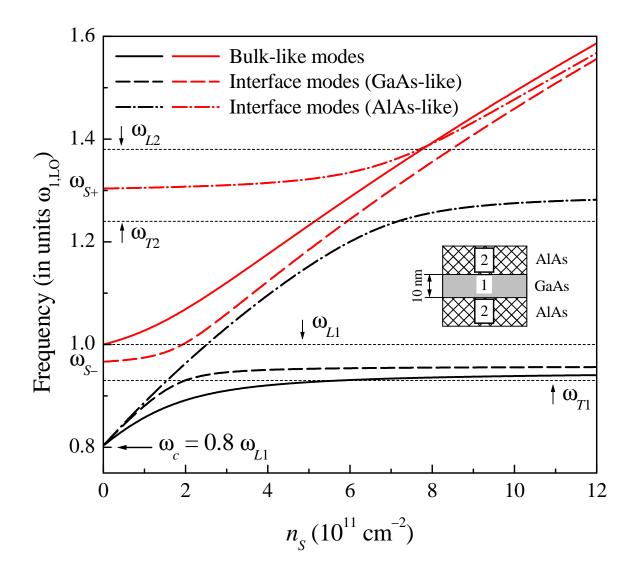


Fig. 1 S. N. Klimin and J. T. Devreese, Physical Review B

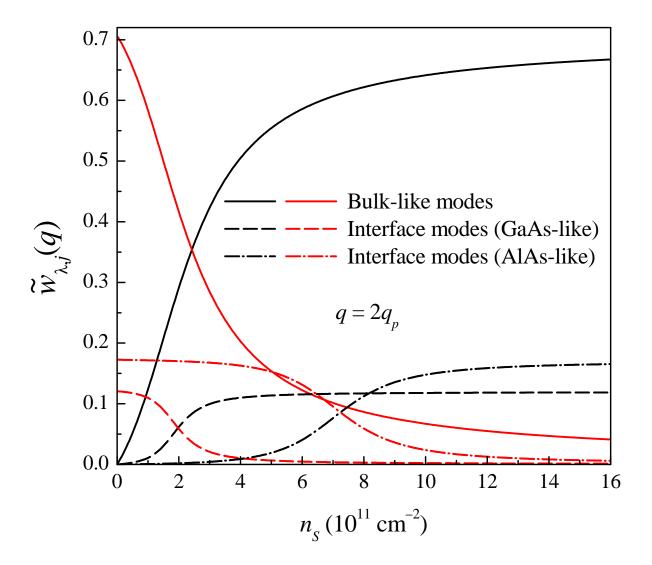


Fig. 2 S. N. Klimin and J. T. Devreese, Physical Review B

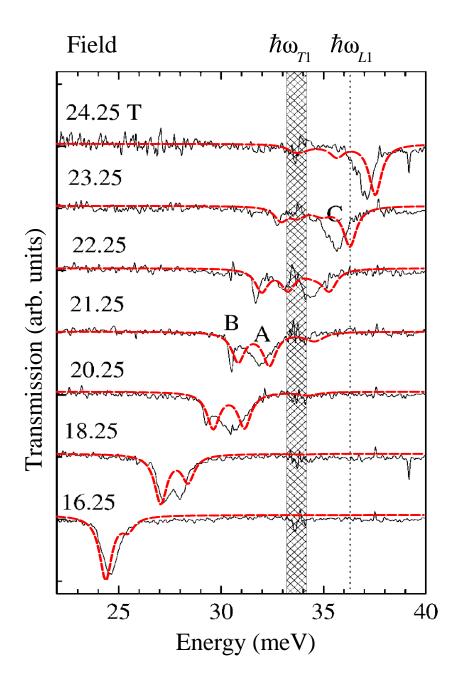


Fig. 3 S. N. Klimin and J. T. Devreese, Physical Review B

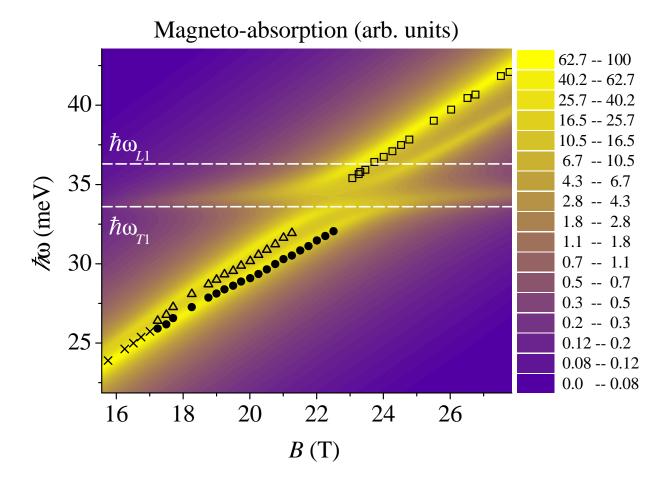


Fig. 4 S. N. Klimin and J. T. Devreese, Physical Review B